



PJM05C20DFA

N and P-Channel Complementary Power MOSFET

Features

- **N-Channel**

$V_{DS}=20V, I_D=5A$

$R_{DS(on)} < 28m\Omega @ V_{GS}=4.5V$

$R_{DS(on)} < 35m\Omega @ V_{GS}=2.5V$

- **P-Channel**

$V_{DS}=-20V, I_D=-5A$

$R_{DS(on)} < 45m\Omega @ V_{GS}=-4.5V$

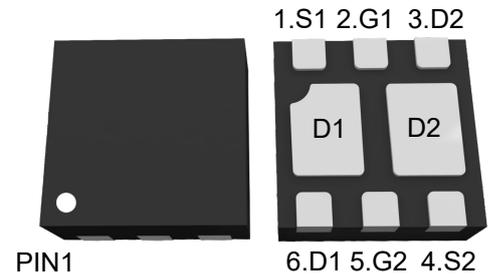
$R_{DS(on)} < 70m\Omega @ V_{GS}=-2.5V$

- Very fast switching
- Trench MOSFET technology

Applications

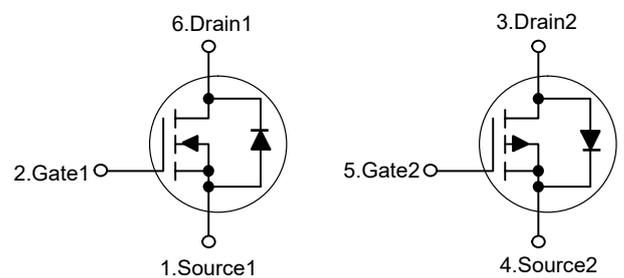
- Switching
- DC/DC Converter

DFN2x2A-6L



Marking Code: 2005

Schematic Diagram



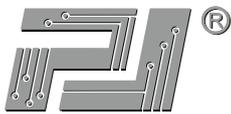
Absolute Maximum Ratings

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	N-Channel	P-Channel	Unit
Drain-Source Voltage	V_{DS}	20	-20	V
Gate-Source Voltage	V_{GS}	± 12	± 12	V
Drain Current-Continuous	I_D	+5	-5	A
Drain Current-Pulsed ^{Note1}	I_{DM}	20	-20	A
Maximum Power Dissipation	P_D	1.2		W
Operating Junction and Storage Temperature Range	T_J, T_{STG}	150, -55~150		°C

Thermal Characteristics

Thermal Resistance, Junction-to-Ambient ^{Note2}	$R_{\theta JA}$	104	°C/W
--	-----------------	-----	------



PJM05C20DFA

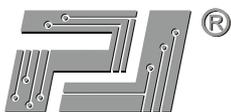
N and P-Channel Complementary Power MOSFET

N-Channel

Electrical Characteristics

($T_a=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	20	--	--	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=20V, V_{GS}=0V$	--	--	1	μA
Gate-Body Leakage Current	I_{GSS}	$V_{GS}=\pm 12V, V_{DS}=0V$	--	--	± 100	nA
Gate Threshold Voltage ^{Note3}	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.5	0.7	1.0	V
Drain-Source On-Resistance ^{Note3}	$R_{DS(on)}$	$V_{GS}=4.5V, I_D=4.5A$	--	--	28	m Ω
		$V_{GS}=2.5V, I_D=4A$	--	--	35	m Ω
Forward Transconductance ^{Note3}	g_{FS}	$V_{DS}=15V, I_D=5A$	--	25	--	S
Dynamic Characteristics						
Input Capacitance	C_{iss}	$V_{DS}=8V, V_{GS}=0V, f=1MHz$	--	500	--	pF
Output Capacitance	C_{oss}		--	295	--	pF
Reverse Transfer Capacitance	C_{rss}		--	96	--	pF
Switching Characteristics						
Turn-on Delay Time	$t_{d(on)}$	$V_{DD}=10V, I_D=1A$ $V_{GS}=4.5V, R_{GEN}=6\Omega$	--	11	--	nS
Turn-on Rise Time	t_r		--	30	--	nS
Turn-off Delay Time	$t_{d(off)}$		--	35	--	nS
Turn-off Fall Time	t_f		--	10	--	nS
Total Gate Charge	Q_g	$V_{DS}=10V, I_D=3A, V_{GS}=4.5V$	--	10	--	nC
Gate-Source Charge	Q_{gs}		--	2.3	--	nC
Gate-Drain Charge	Q_{gd}		--	2.9	--	nC
Source-Drain Diode Characteristics						
Diode Forward Voltage ^{Note3}	V_{SD}	$V_{GS}=0V, I_S=5A$	--	--	1.2	V
Diode Forward Current ^{Note2}	I_S		--	--	5	A



PJM05C20DFA

N and P-Channel Complementary Power MOSFET

P-Channel

Electrical Characteristics

($T_a=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$-V_{(BR)DSS}$	$V_{GS}=0V, I_D=-250\mu A$	20	--	--	V
Zero Gate Voltage Drain Current	$-I_{DSS}$	$V_{DS}=-20V, V_{GS}=0V$	--	--	1	μA
Gate-Body Leakage Current	I_{GSS}	$V_{GS}=\pm 12V, V_{DS}=0V$	--	--	± 100	nA
Gate Threshold Voltage ^{Note3}	$-V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	0.5	0.7	0.9	V
Drain-Source On-Resistance ^{Note3}	$R_{DS(on)}$	$V_{GS}=-4.5V, I_D=-4.1A$	--	--	45	m Ω
		$V_{GS}=-2.5V, I_D=-3A$	--	--	70	m Ω
Forward Transconductance ^{Note3}	g_{FS}	$V_{DS}=-5V, I_D=-4.1A$	--	6	--	S
Dynamic Characteristics						
Input Capacitance	C_{iss}	$V_{DS}=-4V, V_{GS}=0V, f=1MHz$	--	740	--	pF
Output Capacitance	C_{oss}		--	290	--	pF
Reverse Transfer Capacitance	C_{rss}		--	190	--	pF
Switching Characteristics						
Turn-on Delay Time	$t_{d(on)}$	$V_{DD}=-4V, R_L=1.2\Omega$ $V_{GS}=-4.5V, R_{GEN}=1\Omega$	--	12	--	nS
Turn-on Rise Time	t_r		--	35	--	nS
Turn-off Delay Time	$t_{d(off)}$		--	30	--	nS
Turn-off Fall Time	t_f		--	10	--	nS
Total Gate Charge	Q_g	$V_{DS}=-4V, I_D=-4.1A,$ $V_{GS}=-4.5V$	--	7.8	--	nC
Gate-Source Charge	Q_{gs}		--	1.2	--	nC
Gate-Drain Charge	Q_{gd}		--	1.6	--	nC
Source-Drain Diode Characteristics						
Diode Forward Voltage ^{Note3}	$-V_{SD}$	$V_{GS}=0V, I_S=-5A$	--	--	1.2	V
Diode Forward Current ^{Note2}	$-I_S$		--	--	5	A

Note: 1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, $t \leq 10$ sec.

3. Pulse Test: Pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$.

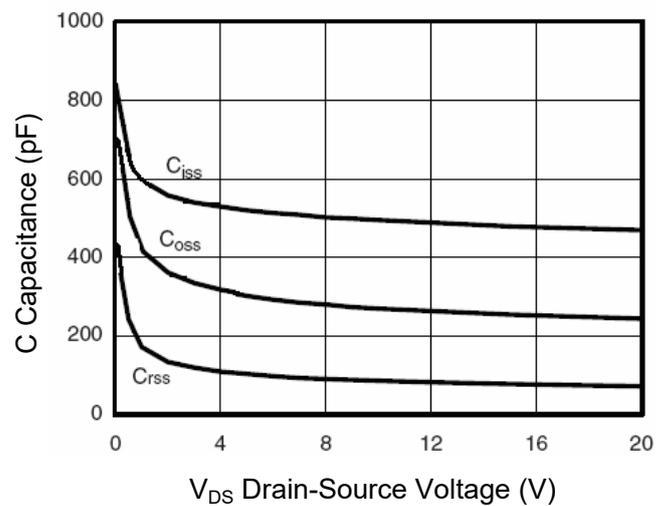
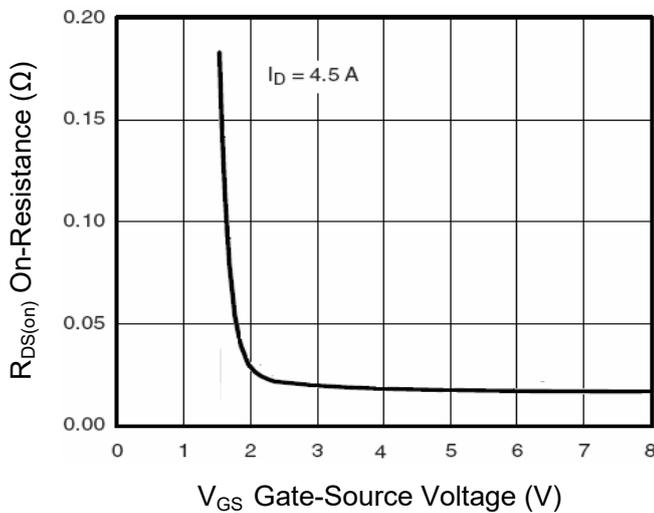
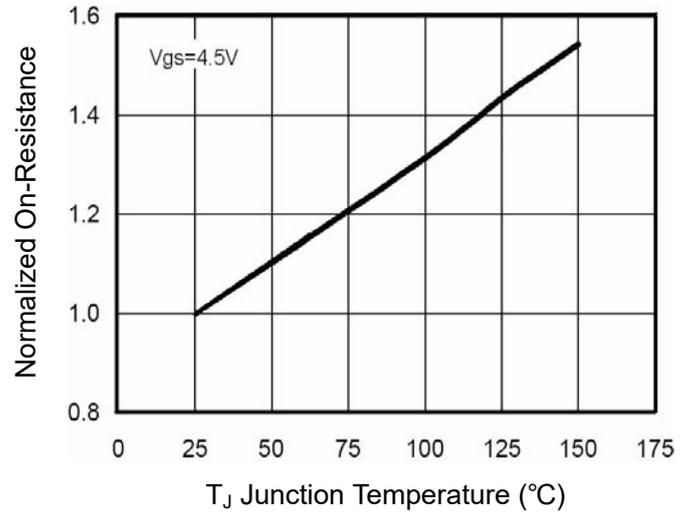
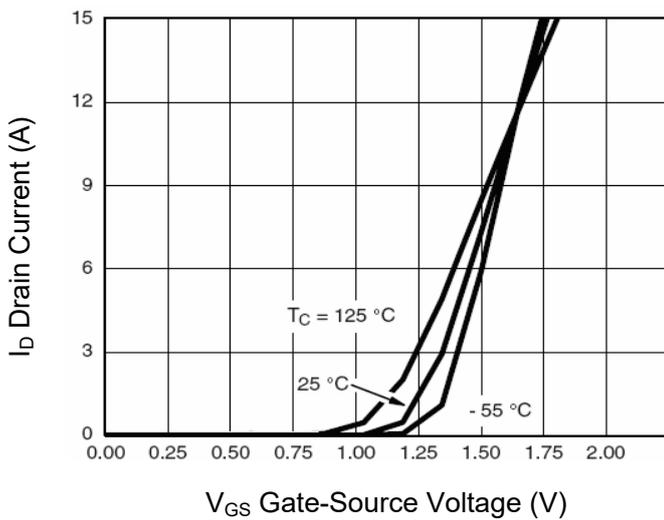
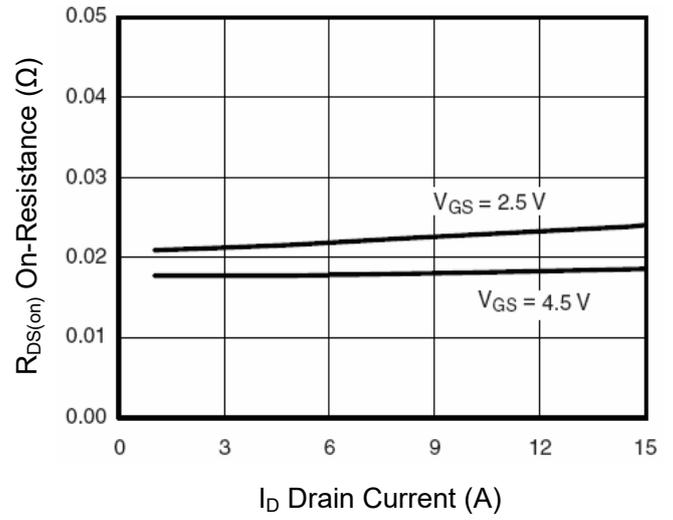
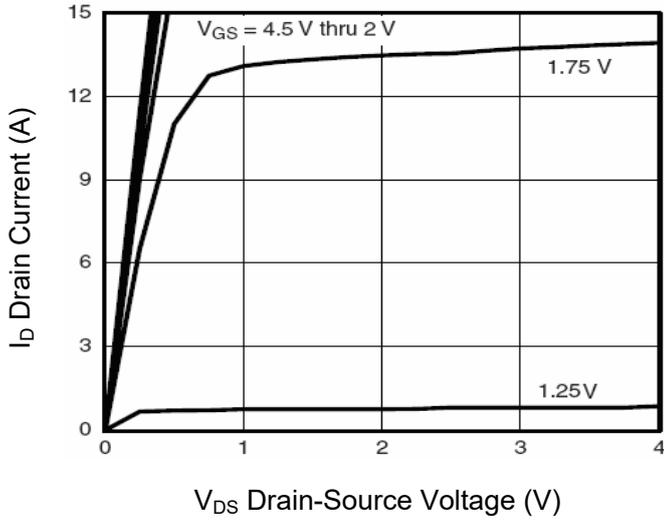


PJM05C20DFA

N and P-Channel Complementary Power MOSFET

N-Channel

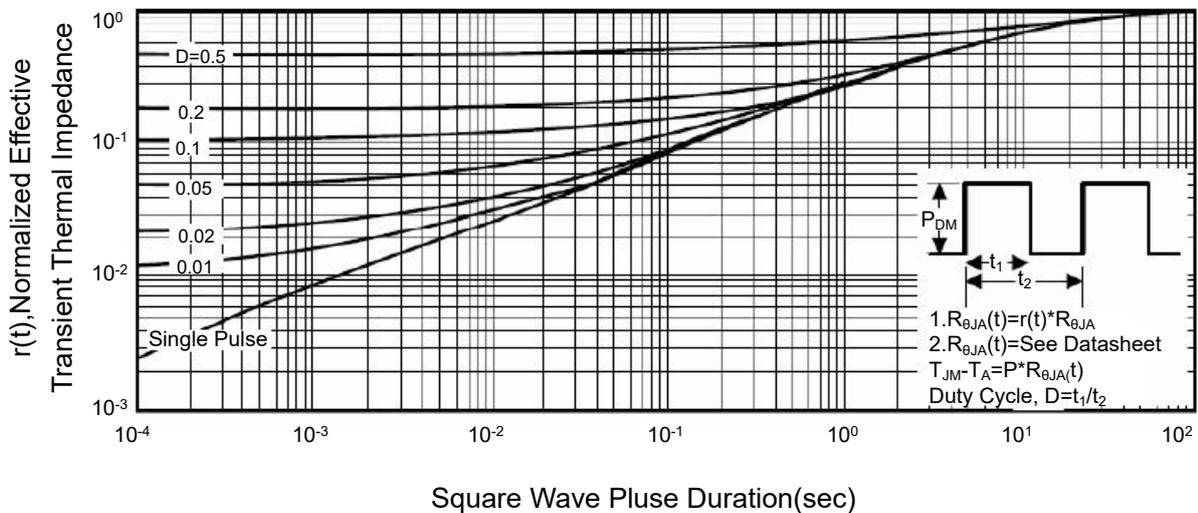
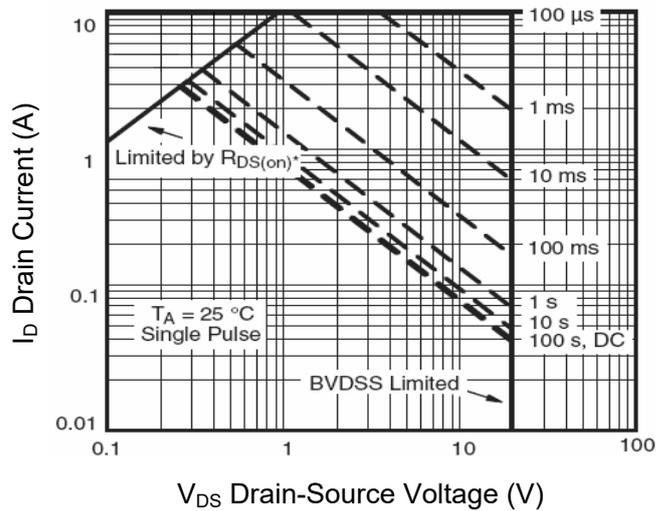
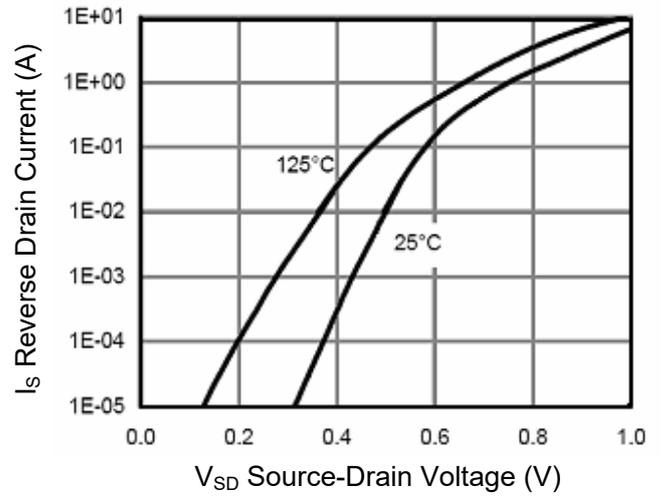
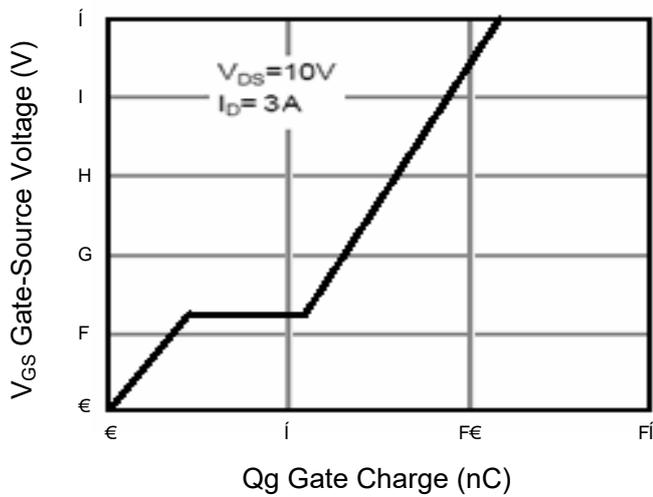
Electrical Characteristics Curves

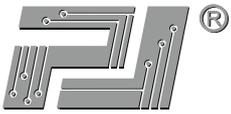




PJM05C20DFA

N and P-Channel Complementary Power MOSFET



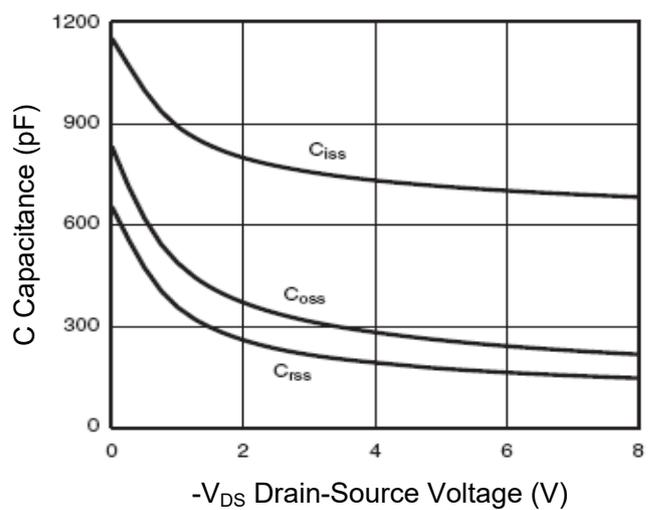
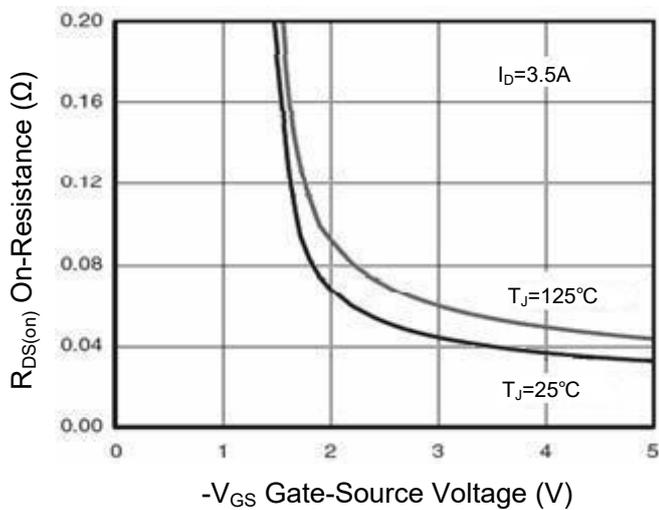
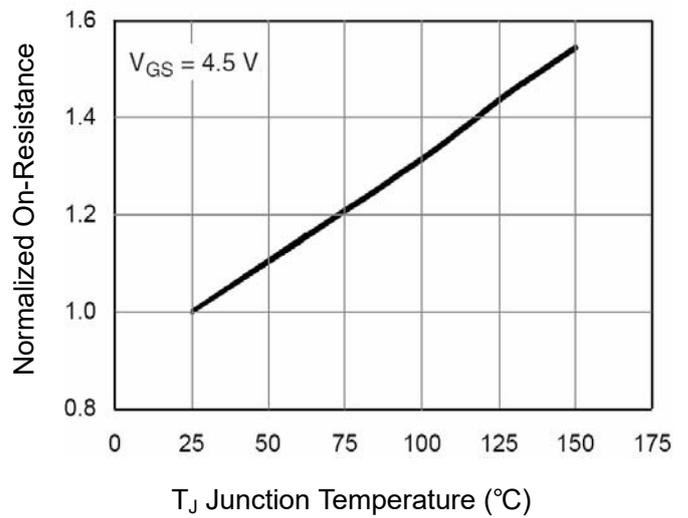
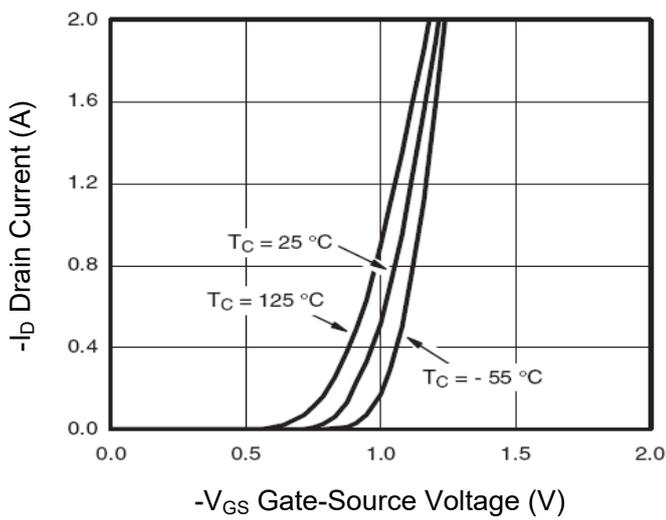
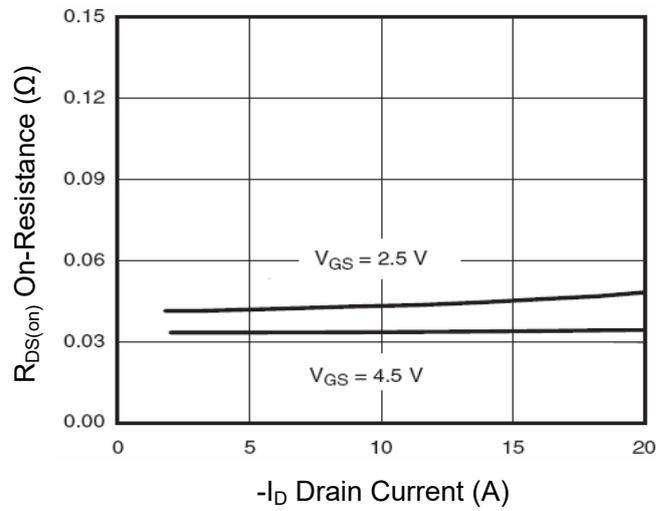
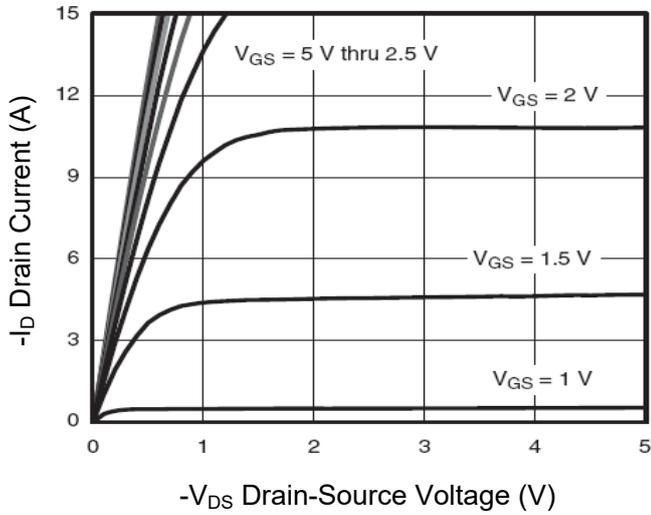


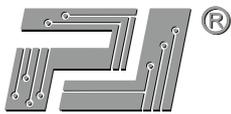
PJM05C20DFA

N and P-Channel Complementary Power MOSFET

P-Channel

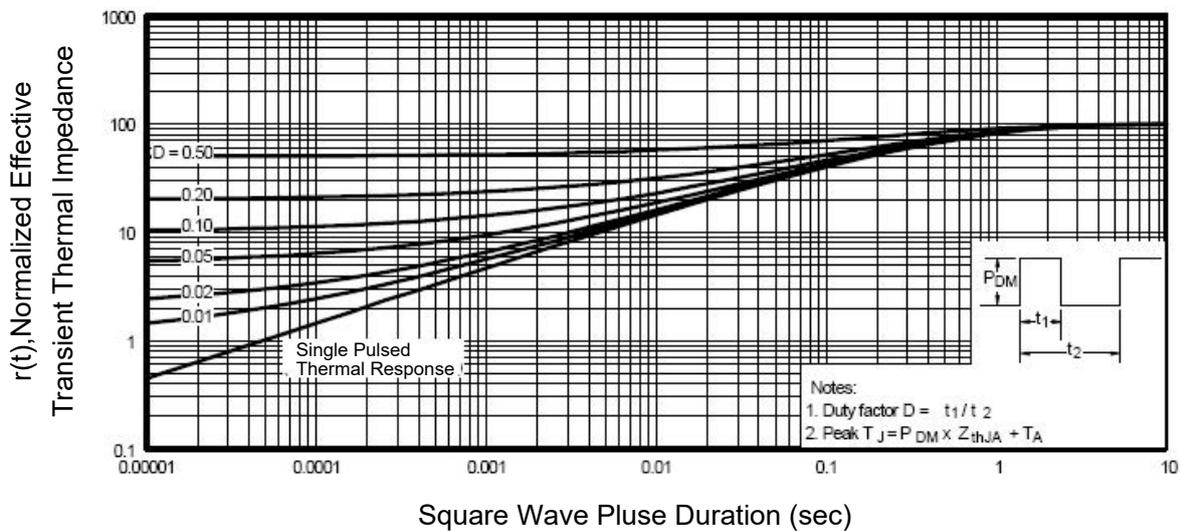
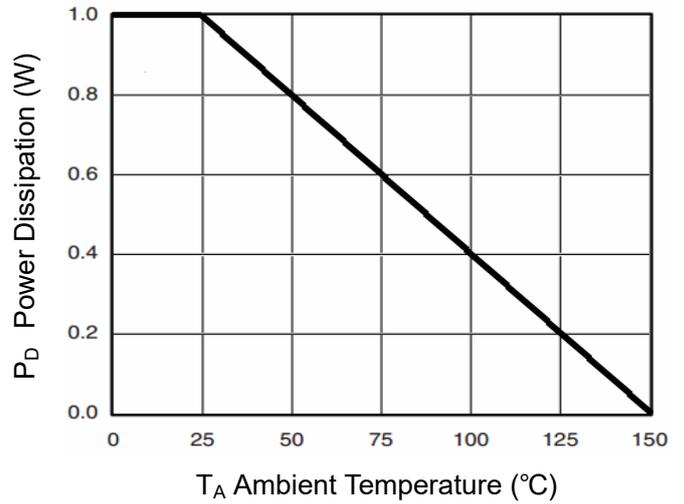
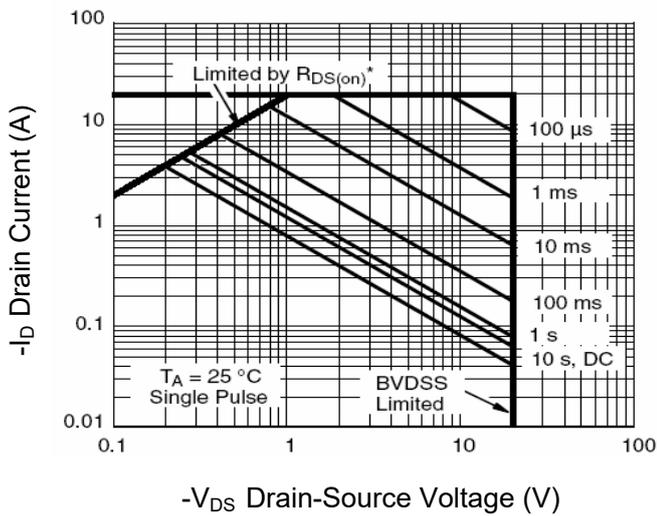
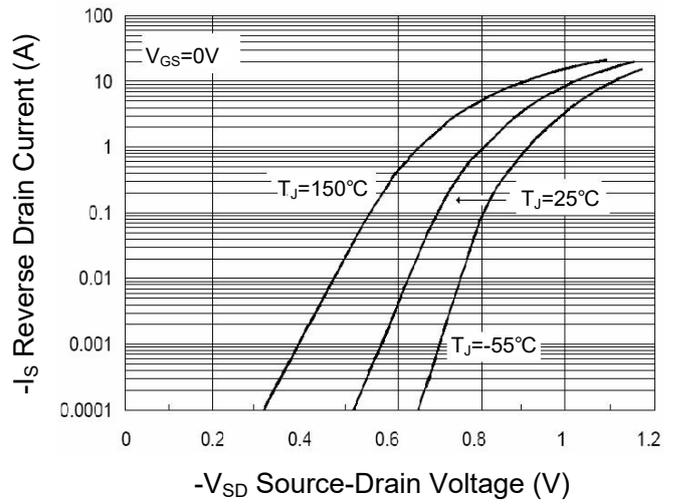
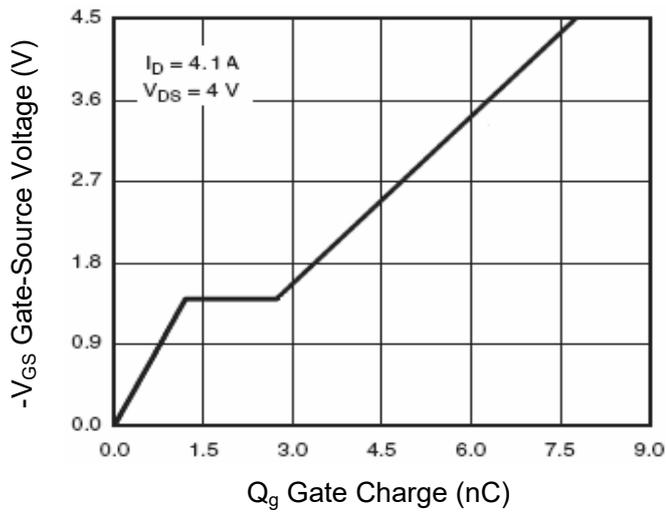
Electrical Characteristics Curves





PJM05C20DFA

N and P-Channel Complementary Power MOSFET





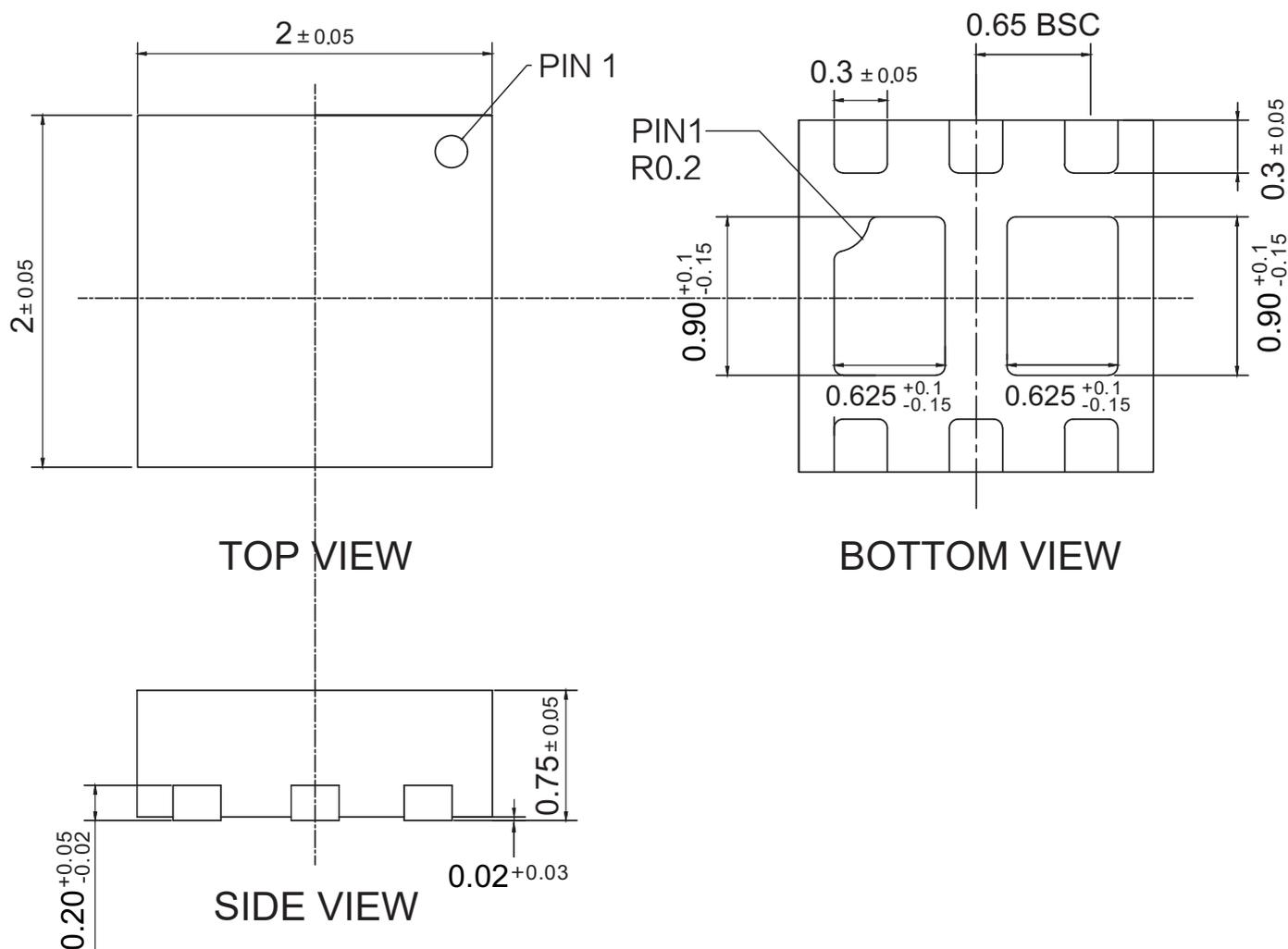
PJM05C20DFA

N and P-Channel Complementary Power MOSFET

Package Outline

DFN2x2-6L-0002

Dimensions in mm



Ordering Information

Device	Package	Shipping
PJM05C20DFA	DFN2x2A-6L	3,000PCS/Reel&7inches

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [MOSFET](#) category:

Click to view products by [Pingjingsemi](#) manufacturer:

Other Similar products are found below :

[IRFD120](#) [JANTX2N5237](#) [BUK455-60A/B](#) [MIC4420CM-TR](#) [VN1206L](#) [NDP4060](#) [SI4482DY](#) [IPS70R2K0CEAKMA1](#) [SQD23N06-31L-GE3](#)
[TK16J60W,S1VQ\(O](#) [2SK2614\(TE16L1,Q\)](#) [DMN1017UCP3-7](#) [DMN1053UCP4-7](#) [SQJ469EP-T1-GE3](#) [NTE2384](#) [DMC2700UDMQ-7](#)
[DMN2080UCB4-7](#) [DMN61D9UWQ-13](#) [US6M2GTR](#) [DMN31D5UDJ-7](#) [DMP22D4UFO-7B](#) [DMN1006UCA6-7](#) [DMN16M9UCA6-7](#)
[STF5N65M6](#) [IRF40H233XTMA1](#) [STU5N65M6](#) [DMN6022SSD-13](#) [DMN13M9UCA6-7](#) [DMTH10H4M6SPS-13](#) [DMN2990UFB-7B](#)
[IPB80P04P405ATMA2](#) [2N7002W-G](#) [MCAC30N06Y-TP](#) [MCQ7328-TP](#) [NTMC083NP10M5L](#) [NVMFS2D3P04M8LT1G](#) [BXP7N65D](#)
[BXP4N65F](#) [AOL1454G](#) [WMJ80N60C4](#) [BXP2N20L](#) [BXP2N65D](#) [BXT1150N10J](#) [BXT1700P06M](#) [TSM60NB380CP](#) [ROG](#) [RQ7L055BGTCR](#)
[DMNH15H110SK3-13](#) [SLF10N65ABV2](#) [BSO203SP](#) [BSO211P](#)